

# **HN3C10FUTE85LF**

### **HN3C10FUTE85LF Information**



For Reference Only

Part Number HN3C10FUTE85LF

Manufacturer Toshiba Semiconductor and Storage
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - RF

DescriptionTRANSISTOR NPN US6Package6-TSSOP, SC-88, SOT-363

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

### **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









### **HN3C10FUTE85LF Specifications**

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Manufacturer Part Number	HN3C10FUTE85LF
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	6-TSSOP, SC-88, SOT-363
Series	-
Transistor Type	2 NPN (Dual)
Voltage - Collector Emitter Breakdown (Max)	12V
Frequency - Transition	7GHz
Noise Figure (dB Typ @ f)	1.1dB @ 1GHz
Gain	11.5dB
Power - Max	200mW
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 20mA, 10V
Current - Collector (Ic) (Max)	80mA
Operating Temperature	-
Mounting Type	Surface Mount
Package / Case	6-TSSOP, SC-88, SOT-363
Supplier Device Package	US6
	Report errors?

#### **HN3C10FUTE85LF Guarantees**



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

### **HN3C10FUTE85LF Payment Methods**



















## **HN3C10FUTE85LF Shipping Methods**













If you have any question about HN3C10FUTE85LF, please do not hesitate to contact us!

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